D, JG, OR P PACKAGE

(TOP VIEW)

BAL1 1

IN. – □2 IN+F

Vcc-[

### LF411C JFET-INPUT OPERATIONAL AMPLIFIER

U 8 ∏NC 7 0 VCC -

5 BAL2

D2997. MARCH 1987-REVISED MAY 1988

- Low Input Bias Current Typically 50 pA
- **Low Input Noise Current** Typically 0.01 pA/√Hz
- Low Supply Current . . . Typically 2.0 mA
- High Input Impedance

NC-No internal connection

- Typically 1012 Ω
- **Low Total Harmonic Distortion**
- Low 1/f Noise Corner . . . Typically 50 Hz

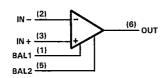
#### description

This device is a low-cost, high-speed, JFET-input operational amplifier with very low input offset voltage and a maximum input offset voltage drift. It requires low supply current yet maintains a large gain-bandwidth product and a fast slew rate. In addition, the matched high-voltage JFET input provides very low input bias and offset currents.

The LF411C can be used in applications such as high-speed integrators, digital-to-analog converters, sampleand-hold circuits, and many other circuits.

The LF411C is characterized for operation from 0°C to 70°C.

#### symbol



#### **AVAILABLE OPTIONS**

	V <sub>{O</sub> MAX AT 25°C	PACKAGE				
TA		SMALL-OUTLINE (D)	CERAMIC DIP (JG)	PLASTIC DIP (P)		
0°C to 70°C	2 mV	LF411CD	LF411CJG	LF411CP		

D package is available taped and reeled. Add "R" suffix to device type. (e.g. LF411CDR)

**Operational Amplifiers** 

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)
Supply voltage, VCC+ 18 V
Supply voltage, VCC18 V
Differential input voltage, VID ±30 V
Input voltage (see Note 1)
Duration of output short circuit
Continuous total power dissipation 500 mW
Operating temperature range
Storage temperature range
Lead temperature 1.6 mm (1/16 inch) from case for 60 seconds, JG package 300°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds, D or P package 260 °C

NOTE 1: Unless otherwise specified, the absolute maximum negative input voltage is equal to the negative power supply voltage.

# electrical characteristics over operating free-air temperature range, $V_{CC+} = 15 \text{ V}$ , $V_{CC-} = -15 \text{ V}$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
VIO	Input offset voltage	V <sub>IC</sub> = 0,	$R_S = 10 k\Omega$ ,	$T_A = 25$ °C	0.8		2	mV
αVIO	Average temperature coefficient of input offset voltage	V <sub>IC</sub> = 0,	R <sub>S</sub> = 10 kΩ			10	20 <sup>†</sup>	μV/°C
lıo	Input offset current <sup>‡</sup>	V <sub>IC</sub> = 0		Tj = 25°C		25	100	pΑ
				T <sub>J</sub> = 70°C			2	nA
I <sub>IB</sub>	Input bias current <sup>‡</sup>	V <sub>IC</sub> = 0		T <sub>J</sub> = 25°C		50	200	pΑ
				T <sub>J</sub> = 70°C			4	nA
VICR (	Common-mode input voltage range				-11.5			
					±11	to		v
					ļ <u>.</u>	14.5		
Vом	Maximum peak output voltage swing	R <sub>L</sub> = 10 kΩ			±12	±13.5		·V
AVD	Large-signal differential voltage	$V_0 = \pm 10 \text{ V},  R_L = 2 \text{ k}\Omega$	D. 010	$T_A = 25$ °C	25	200		V/mV
			Full range	15	200			
ri	Input resistance	T <sub>J</sub> = 25°C				1012	·	Ω
CMRR	Common-mode rejection ratio	R <sub>S</sub> ≤ 10 kΩ			70	100		dB
ksvr	Supply voltage rejection ratio	See Note 2			70	100		dB
Icc	Supply current					2	3.4	mA

## operating characteristics, $V_{CC+} = 15 \text{ V}$ , $V_{CC-} = -15 \text{ V}$ , $T_A = 25 ^{\circ}C$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		8	13		V/μs
B <sub>1</sub>	Unity-gain bandwidth		2.7	3		MHz
V <sub>n</sub>	Equivalent input noise voltage	$f = 1 \text{ kHz}, R_S = 100 \Omega$		18		nV/√Hz
la.	Equivalent input noise current	f = 1 kHz		0.01		pA/√Hz

NOTE 2: Supply voltage rejection ratio is measured for both supply magnitudes increasing or decreasing simultaneously.



<sup>†</sup> At least 90% of the devices meet this limit for aVIO.
‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperatures as close to the ambient temperature as possible.